Preferred Device

Triacs

Silicon Bidirectional Thyristors

Designed primarily for full wave ac control applications, such as motor controls, heating controls or dimmers; or wherever full-wave, silicon gate-controlled devices are needed.

- High Commutating di/dt and High Immunity to dV/dt @ 125°C
- Minimizes Snubber Networks for Protection
- Blocking Voltage to 800 Volts
- On-State Current Rating of 16 Amperes RMS
- High Surge Current Capability 150 Amperes
- Industry Standard TO-220AB Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity
- Operational in Three Quadrants, Q1, Q2, and Q3
- Device Marking: Logo, Device Type, e.g., MAC16CM, Date Code

MAXIMUM RATINGS (T_J = 25°C unless otherwise noted)

Rating	Symbol	Value	Unit
Peak Repetitive Off-State Voltage (Note 1) (T _J = -40 to 125°C) MAC16CM MAC16CN	V _{DRM,} V _{RRM}	600 800	Volts
On-State RMS Current (Full Cycle Sine Wave 50 to 60 Hz; T _C = 80°C)	I _{T(RMS)}	16	А
Peak Non-Repetitive Surge Current (One Full Cycle, 60 Hz, T _J = 125°C)	I _{TSM}	150	А
Circuit Fusing Consideration (t = 8.33 ms)	l ² t	93	A ² sec
Peak Gate Power (Pulse Width ≤ 1.0 μs, T _C = 80°C)	P _{GM}	20	Watts
Average Gate Power (t = 8.3 ms, T _C = 80°C)	P _{G(AV)}	0.5	Watts
Operating Junction Temperature Range	TJ	-40 to +125	°C
Storage Temperature Range	T _{stg}	-40 to +150	°C

V_{DRM} and V_{RRM} for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

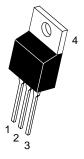


ON Semiconductor®

http://onsemi.com

TRIACS 16 AMPERES RMS 400 thru 800 VOLTS





TO-220AB CASE 221A STYLE 4

PIN ASSIGNMENT				
1	Main Terminal 1			
2	Main Terminal 2			
3	Gate			
4	Main Terminal 2			

ORDERING INFORMATION

Device	Package	Shipping
MAC16CM	TO220AB	50 Units/Rail
MAC16CN	TO220AB	50 Units/Rail

Preferred devices are recommended choices for future use and best overall value.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Value	Unit
Thermal Resistance			°C/W
- Junction to Case	$R_{\theta JC}$	2.2	
- Junction to Ambient	$R_{\theta JA}$	62.5	
Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds	TL	260	°C

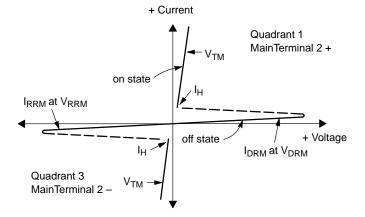
ELECTRICAL CHARACTERISTICS ($T_J = 25^{\circ}C$ unless otherwise noted; Electricals apply in both directions)

Characteristic		Min	Тур	Max	Unit
OFF CHARACTERISTICS			1		
Peak Repetitive Blocking Current $(V_D = Rated \ V_{DRM}, \ V_{RRM} \ Gate \ Open) \\ T_J = 25^{\circ}C \\ T_J = 125^{\circ}C$	I _{DRM,} I _{RRM}	- -	_ _	0.01 2.0	mA
ON CHARACTERISTICS					
Peak On-State Voltage (Note 2) (I _{TM} = ±21 A Peak)	V _{TM}	_	1.2	1.6	V
Gate Trigger Current (Continuous DC) $(V_D=12\ V,\ R_L=100\ \Omega) \\ MT2(+),\ G(+) \\ MT2(+),\ G(-) \\ MT2(-),\ G(-)$	I _{GT}	8.0 8.0 8.0	12 16 20	35 35 35	mA
Holding Current ($V_D = 12 \text{ V}$, Gate Open, Initiating Current = $\pm 150 \text{ mA}$)	I _H	-	20	50	mA
Latching Current ($V_D = 12 \text{ V}, I_G = 35 \text{ mA}$) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)	ΙL	- - -	25 40 24	50 80 50	mA
Gate Trigger Voltage (Continuous DC) $ \begin{aligned} &(V_D=12\ V,\ R_L=100\ \Omega)\\ &MT2(+),\ G(+)\\ &MT2(+),\ G(-)\\ &MT2(-),\ G(-) \end{aligned} $	V _{GT}	0.5 0.5 0.5	0.75 0.72 0.82	1.5 1.5 1.5	V
DYNAMIC CHARACTERISTICS	-			•	
Rate of Change of Commutating Current ($V_D = 400~V,~I_{TM} = 6.0~A,~Commutating~dV/dt = 24~V/\mu s,~Gate~Open,~T_J = 125°C,~f = 250~Hz,~C_L = 10~\mu F,~L_L = 40~mH,~with~Snubber)$	(di/dt) _c	15	-	_	A/ms
Critical Rate of Rise of Off-State Voltage $(V_D = Rated\ V_{DRM}, Exponential\ Waveform, Gate\ Open,\ T_J = 125°C)$	dV/dt	600	-	_	V/µs
Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 µsec; diG/dt = 200 mA/µsec; f = 60 Hz	di/dt	-	-	10	A/μs

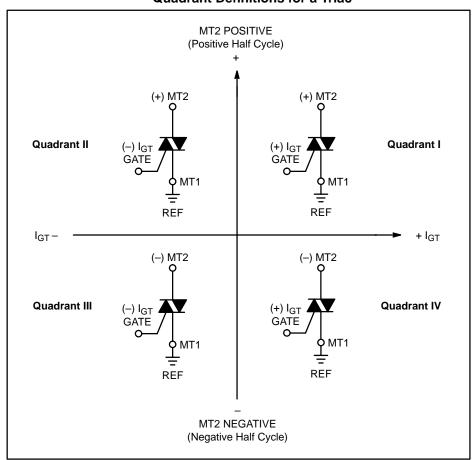
^{2.} Pulse Test: Pulse Width \leq 2.0 ms, Duty Cycle \leq 2%.

Voltage Current Characteristic of Triacs (Bidirectional Device)

Symbol	Parameter
V_{DRM}	Peak Repetitive Forward Off State Voltage
I _{DRM}	Peak Forward Blocking Current
V _{RRM}	Peak Repetitive Reverse Off State Voltage
I _{RRM}	Peak Reverse Blocking Current
V_{TM}	Maximum On State Voltage
lΗ	Holding Current



Quadrant Definitions for a Triac



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

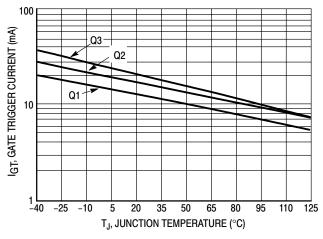


Figure 1. Typical Gate Trigger Current versus Junction Temperature

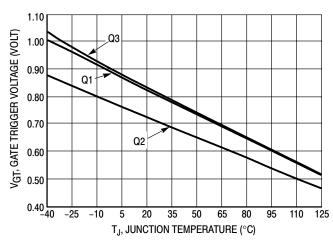


Figure 2. Typical Gate Trigger Voltage versus Junction Temperature

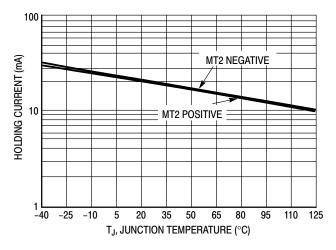


Figure 3. Typical Holding Current versus Junction Temperature

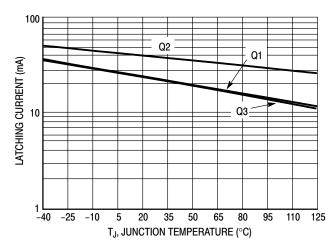


Figure 4. Typical Latching Current versus Junction Temperature

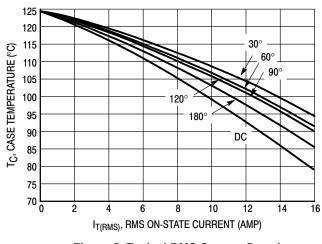


Figure 5. Typical RMS Current Derating

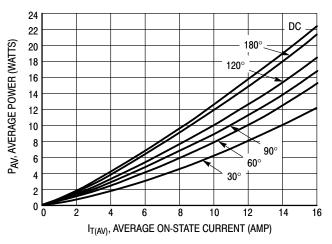


Figure 6. On-State Power Dissipation

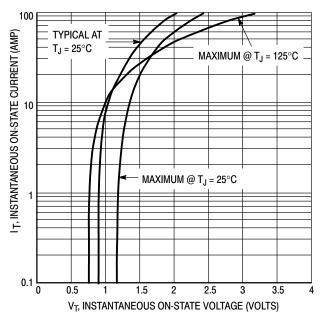


Figure 7. On-State Characteristics

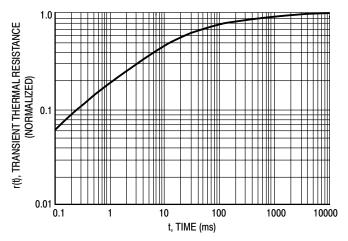
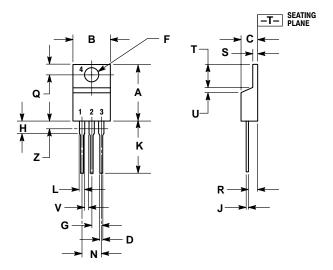


Figure 8. Typical Thermal Response

PACKAGE DIMENSIONS

TO-220AB

CASE 221A-09 **ISSUE AA**



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

	INC	INCHES MILLIMETERS		IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.570	0.620	14.48	15.75
В	0.380	0.405	9.66	10.28
С	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
Н	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
٧	0.045		1.15	
Z		0.080		2.04

- STYLE 4:
 PIN 1. MAIN TERMINAL 1
 2. MAIN TERMINAL 2
 3. GATE
 4. MAIN TERMINAL 2



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